

Preliminary Data Sheet

1N5391 THRU 1N5399 1.5AMP. Standard Silicon Rectifiers

VOLTAGE:50 TO 1000V CURRENT:1.5A

AXIAL LEAD DO-15

Specification Features:

Case: Epoxy, Molded

Weight: 0.4Gram (Approximately)

High current capability, Low leakage current

High surge current capability

 Finish: All External Surfaces Corrosion Resistant And Terminal Leads Are Readily Solderable

Lead And Mounting Surface Temperature For Soldering Purposed:

260°C Max. For 10 Seconds 1/16 Inch From Case

RoHS Compliant
 Cathode Indicated By Polarity Band

DEVICE MARKING DIAGRAM



1N53XX : Device Name 1N5391~1N5399

KEL : KEL Logo

Absolute Maximum Ratings T_A = 25°C unless otherwise noted

ADSOIDLE MAXIIIIUIII Natiilys	r _A = 25 C unless otherwise noted								
Parameter	Symbol	1N 5391	1N 5392	1N 5393	1N 5395	1N 5397	1N 5398	1N 5399	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum DC Blocking Voltage	V_{R}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectifier Current. (0.375" Lead Length @ T _A =75℃)	$I_{F(AV)}$	1.5							А
Non-repetitive Peak Forward Surge Current. (8.3mS Single Half Sine-wave)	I _{FSM}	50							А
Operating Junction and Storage Temperature Range	$T_{J,}T_{STG}$	-65 to +150							°C
Thermal Resistance (Note 1) (Junction to Ambient)	$R_{\theta JA}$	50							°C/W

Electrical Characteristics T_A = 25°C unless otherwise noted

Parameter	Symbol	1N 5391	1N 5392	1N 5393	1N 5395	1N 5397	1N 5398	1N 5399	Units
Reverse Current @V _R	I _R				5				uA
Forward Voltage @1.5A	V _F				1.1				V
Total Capacitance (Note 2) @VR=4V, f=1MHz	Ст				25				pF

NOTE: (1) Thermal resistance from junction to ambient at 0.375" lead length, vertical P.C. board mounted

(2) Measured at 1 MHz and applied reverse voltage of 4.0V D.C.



Package Outline

